

3.3V, PCI Express® 3.0 2-Lane, 2:1 Mux/DeMux Switch

Features

→ 4 Differential Channel, 2:1 Mux/DeMux

→ PCI Express[®] 3.0 Performance, 8.0Gbps

→ Pinout optimized for placement between two PCIe slots

→ Bi-directional operation

→ Low Bit-to-Bit Skew, 10ps max

→ Low Crosstalk: -48dB @4GHz

→ High Off Isolation: -22dB @4GHz

→ Low Insertion Loss: -1.6dB @4GHz

→ Return Loss: -15dB @4GHz

→ V_{DD} Operating Range: +3.3V

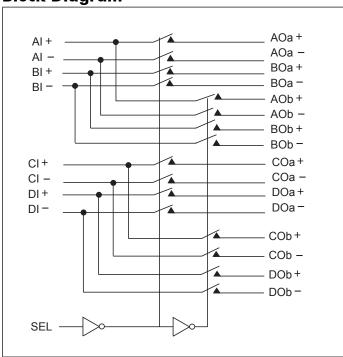
→ ESD Tolerance: 2kV HBM

→ Low channel-to-channel skew, 20ps max

→ Packaging (Pb-free & Green):

42-contact, TQFN (ZH42)

Block Diagram



Truth Table

Function	SEL				
xIy to xOay	L				
xIy to xOby	Н				

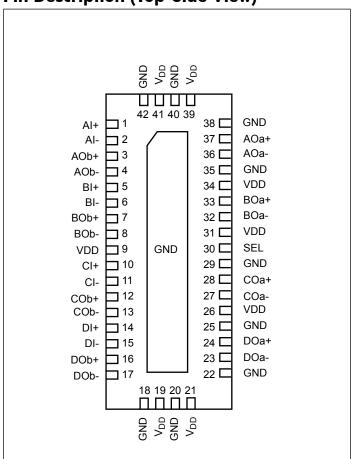
Description

Pericom Semiconductor's PI3PCIE3415 is an 8 to 4 differential channel multiplexer/demultiplexer switch. This solution can switch 2 full PCI Express® 3.0, lanes to one of two locations. Using a unique design technique, Pericom has been able to minimize the impedance of the switch such that the attenuation observed through the switch is negligible. The unique design technique also offers a layout targeted for PCI Express signals, which minimizes the channel to channel skew as well as channel to channel crosstalk as required by the PCI Express specification.

Application

Routing of PCI Express 3.0, DP1.2, USB3.0, SAS2.0, SATA3.0, XAUI, RXAUI signals with low signal attenuation.

Pin Description (Top-Side View)





Signal Descriptions

Pin Number	Pin Name	Туре	Description
1, 2	AI+, AI-	Differential I/O	Differential I/O pair from PCIE signal source. Signal is routed to the AOa+, AOa- pin respectively when SEL=0. Signal is routed to the AOb+, AOb- pin respectively when SEL = 1.
37, 36	AOa+, AOa-	Differential I/O	Differential analog pass-through I/O. Signal from AI+ and AI-is routed to AOa+ and AOa- respectively when SEL=0.
3, 4	AOb+, AOb-	Differential I/O	Differential analog pass-through I/O. Signal from AI+ and AI- is routed to AOb+ and AOb- respectively when SEL=1.
5, 6	BI+, BI-	Differential I/O	Differential I/O pair from PCIE signal source. Signal is routed to the BOa+, BOa- pin respectively when SEL=0. Signal is routed to the BOb+, BOb- pin respectively when SEL = 1.
33, 32	BOa+, BOa-	Differential I/O	Differential analog pass-through I/O. Signal from BI+ and BI- is routed to BOa+ and BOa- respectively when SEL=0.
7, 8	BOb+, BOb-	Differential I/O	Differential analog pass-through I/O. Signal from BI+ and BI- is routed to BOb+ and BOb- respectively when SEL=1.
10, 11	CI+, CI-	Differential I/O	Differential I/O pair from PCIE signal source. Signal is routed to the COa+, COa- pin respectively When SEL=0. Signal is routed to the COb+, COb- pin respectively when SEL = 1.
28, 27	COa+, COa-	Differential I/O	Differential analog pass-through I/O. Signal from CI+ and CI- is routed to COa+, COa- pin respectively when SEL = 0.
12, 13	COb+, COb-	Differential I/O	Differential analog pass-through I/O. Signal from CI+ and CI- is routed to COb+, COb- pin respectively when SEL = 1.
14, 15	DI+, DI-	Differential I/O	Differential I/O pair from PCIE signal source. Signal is routed to the DOa+, DOa- pin respectively When SEL=0. Signal is routed to the DOb+, DOb- pin respectively when SEL = 1.
24, 23	DOa+, DOa-	Differential I/O	Differential analog pass-through I/O. Signal from DI+ and DI- is routed to DOa+, DOa- pin respectively when SEL = 0.
16, 17	DOb+, DOb-	Differential I/O	Differential analog pass-through I/O. Signal from DI+ and DI- is routed to DOb+, DOb- pin respectively when SEL = 1.
18, 20, 22, 25, 29, 35, 38, 40, 42	GND	Ground input	Ground
30	SEL	3.6V tolerant low-voltage single-ended input	SEL controls the mux through a flow-through latch.
9, 19, 21, 26, 31, 34, 39, 41	VDD	Power supply	Power, 3.3V ±10%



Maximum Ratings

(Above which useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	65°C to +150°C
Supply Voltage to Ground Potential	0.5V to +4.6V
Channel DC Input Voltage	0.5V to 1.5V
DC Output Current	120mA
Power Dissipation	0.5W
SEL DC Input Voltage	0.5V to 4.6V

Note: Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Electrical Characteristics Recommended Operating Conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V_{DD}	3.3V Power Supply		3.0	3.3	3.6	V
I_{DD}	Total current from V _{DD} 3.3V supply	SEL = 0V or V _{DD}	0	0.15	1	mA
T _{CASE}	Case temperature range for operation within spec.		-40		85	Celsius

DC Electrical Characteristics $(T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}, V_{DD} = 3.3\text{V} \pm 10\%)$

Parameter	Description	Test Conditions	Min	Typ ⁽¹⁾	Max	Units
V _{IH-SEL}	Input high level, SEL input		2.0		3.6	V
$V_{\text{IL-SEL}}$	Input Low Level, SEL input		0		0.8	V
I _{IN_SEL}	Input Leakage Current, SEL input	Measured with input at VIH-SEL max and VIL-SEL min	-10		10	uA
I_{IH}	Input High Current, xI, xO	$V_{DD} = Max, V_{IN} = 1.5V$	-10		10	uA
I_{IL}	Input Low Current, xI, xO	$V_{DD} = Max, V_{IN} = 0V$	-10		10	uA
I_{IH}	Input High Current, SEL	$V_{DD} = Max, V_{IN} = V_{DD}$	-5		5	uA
I_{IL}	Input Low Current, SEL	$V_{DD} = Max, V_{IN} = 0V$	-5		5	uA
I _{OZH}	HighZ High Current xOa, xOb	$V_{DD} = Max, V_{IN} = 1.5V$	-10		10	uA
I _{OZL}	HighZ Low Current xOa, xOb	$V_{DD} = Max, V_{IN} = 0V$	-10		10	uA

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Note:

1. Typical values are at $V_{DD} = 3.3V$, $T_A = 25$ °C ambient and maximum loading.



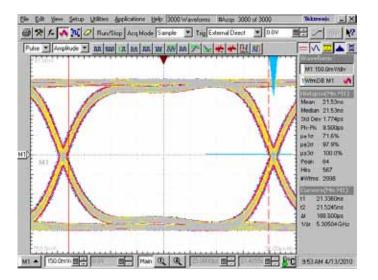
Dynamic Electrical Characteristics for xI+/-, xOy+/-

Parameter	Description	Test Conditions	Min.	Typ.(1)	Max.	Units
DDU		f=50MHz -1.25GHz		-0.8	-1.0	
	Differential Insertion Loss	f=1.25GHz - 2.5GHz		-1.1	-1.3	
DDIL	Differential Insertion Loss	f=2.5GHz - 4GHz		-1.6	-1.9	
		f=5.0GHz		-1.7	-2.0	
			-25.8	-32.2		
DDII	Differential Off Isolation	f= 0 to 4.0GHz	-20.6	-25.8		
DDIL _{OFF}	Differential Off Isolation	1= 0 to 4.0GHZ	-17.6	-22.0		
			-15.4	-19.3		10
		f=50MHz - 1.25GHz	-18.2	-22.7		dB
DDDI	D'G ('ID (I	f=1.25GHz - 2.5GHz	-16.8	-21.0		
DDRL	Differential Return Loss	f=2.5GHz - 4GHz	-12	-15.0		
		f=5.0GHz	-8	-10.0		
		f=50MHz -1.25GHz	-44.8	-56		
DDNEXT	N F 10 (1)	f=1.25GHz - 2.5GHz	-41.6	-52		
	Near End Crosstalk	f=2.5GHz - 4GHz	-38.4	-48		
		f=5.0GHz	-36	-45		
BW	Bandwidth -3dB			8.7		GHz

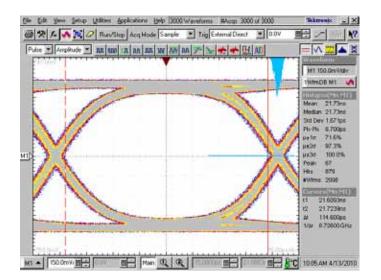
Switching Characteristics

Parameter	Description	Test Conditions	Min.	Тур.	Max.	Units
		See "Test Circuit for	0.5	1.5	25	ns
t_{PZH}, t_{PZL}	Line Enable Time - SEL to xI+/-, xOy+/-	Electrical Characteristics"	0.5 15			
1: D: 11 T: 0TI . 1 . 0 . /		See "Test Circuit for		_	25	
tPHZ, tPLZ	t_{PHZ}, t_{PLZ} Line Disable Time - SEL to xI+/-, xOy+/-	Electrical Characteristics"	0.5	5	25	ns
4	Bit-to-bit skew within the same differential	See "Test Circuit for	4	4	10	
t _{b-b}	pair	Electrical Characteristics"		4	10	ps
t _{ch-ch}	Channel-to-channel skew	See "Test Circuit for			20	
		Electrical Characteristics"				ps

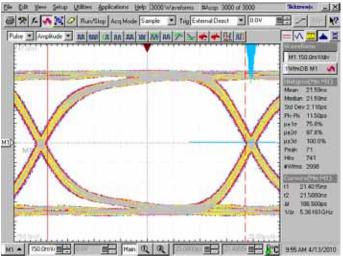




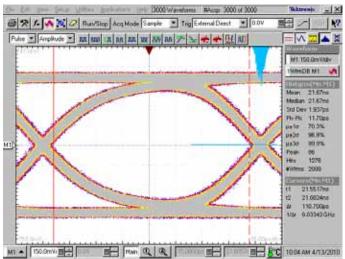
5.0 Gbps RX signal eye without PI3PCIE3415



8.0 Gbps RX signal eye without PI3PCIE3415

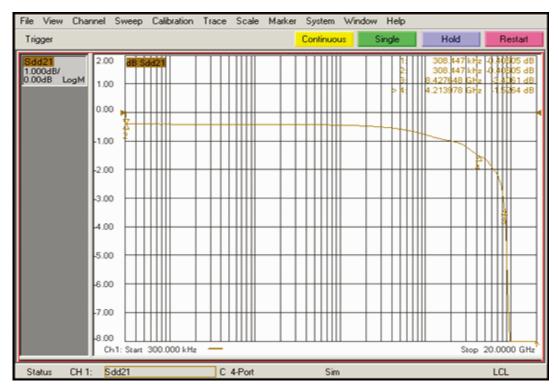


5.0 Gbps RX signal eye with PI3PCIE3415

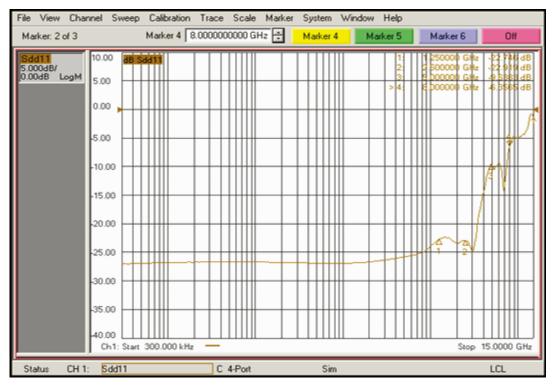


8.0 Gbps RX signal eye with PI3PCIE3415



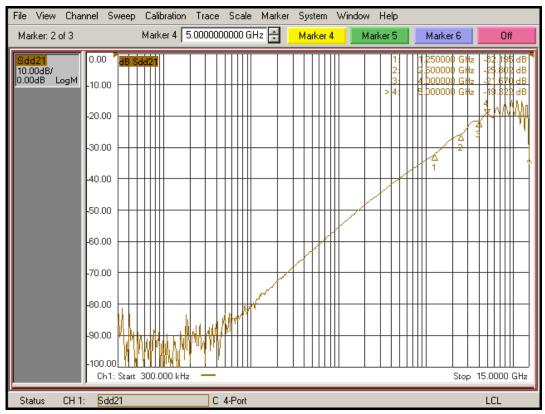


Differential Insertion Loss

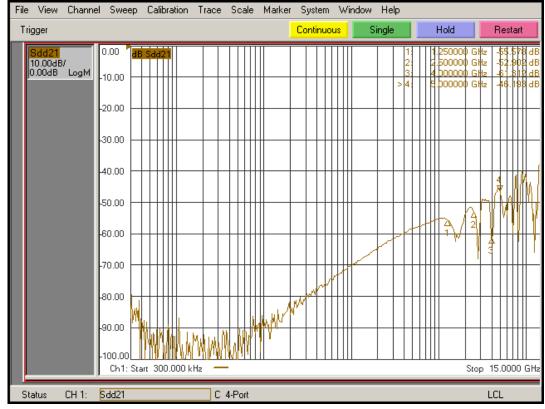


Differential Return Loss





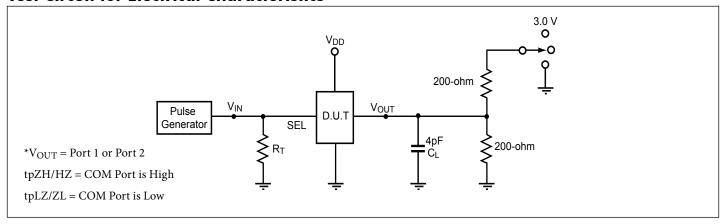
Differential Off Isolation



Differential Crosstalk



Test Circuit for Electrical Characteristics $^{(1-5)}$



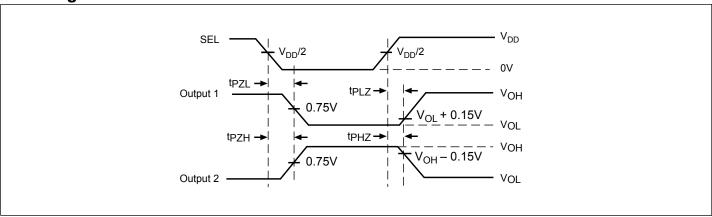
Notes:

- C_L = Load capacitance: includes jig and probe capacitance. 1.
- 2. R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator
- 3. Output 1 is for an output with internal conditions such that the output is low except when disabled by the output control. output 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- 4. All input impulses are supplied by generators having the following characteristics: $PRR \leq MHz, Z_O = 50\Omega, t_R \leq 2.5ns, t_F \leq 2.5ns.$
- 5. The outputs are measured one at a time with one transition per measurement.

Switch Positions

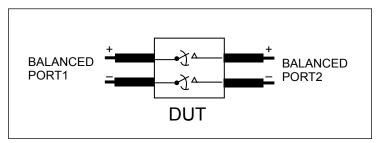
Test	Switch
$t_{\mathrm{PLZ}}, t_{\mathrm{PZL}}$	3.0V
$t_{\mathrm{PHZ}}, t_{\mathrm{PZH}}$	GND

Switching Waveforms

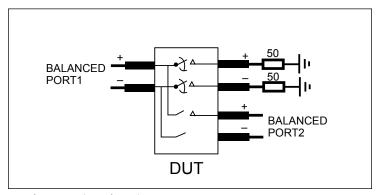


Voltage Waveforms Enable and Disable Times

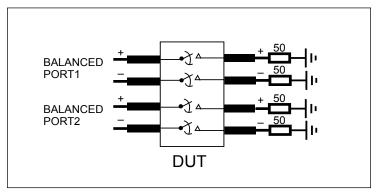




Differential Insertion Loss and Return Test Circuit

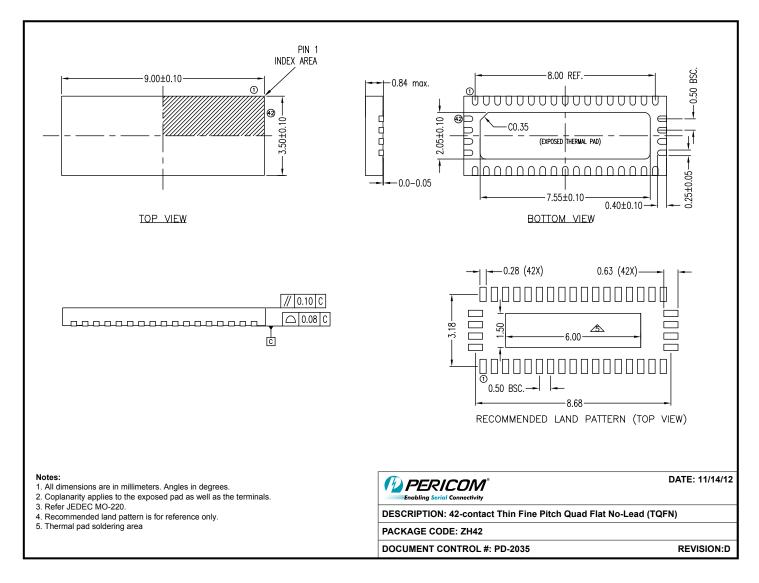


Differential Off Isolation Test Circuit



Differential Near End Xtalk Test Circuit





Note:

For latest package info, please check: http://www.pericom.com/products/packaging/mechanicals.php

Ordering Information

Ordering Code	Package Code	Package Description
PI3PCIE3415ZHE	ZH	Pb-free & Green, 42-contact TQFN

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Notes:

- Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
- "E" denotes Pb-free and Green
- Adding an "X" at the end of the ordering code denotes tape and reel packaging